

# BC817; BC817W; BC337

45 V, 500 mA NPN general-purpose transistors

Rev. 06 — 17 November 2009

Product data sheet

## 1. Product profile

### 1.1 General description

NPN general-purpose transistors.

Table 1. Product overview

| Type number          | Package       |        | PNP complement |
|----------------------|---------------|--------|----------------|
|                      | NXP           | JEITA  |                |
| BC817                | SOT23         | -      | BC807          |
| BC817W               | SOT323        | SC-70  | BC807W         |
| BC337 <sup>[1]</sup> | SOT54 (TO-92) | SC-43A | BC327          |

[1] Also available in SOT54A and SOT54 variant packages (see [Section 2](#)).

### 1.2 Features

- High current
- Low voltage

### 1.3 Applications

- General-purpose switching and amplification

### 1.4 Quick reference data

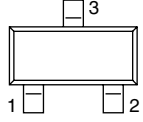
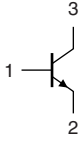
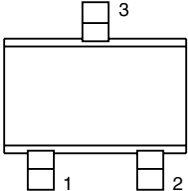
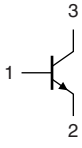
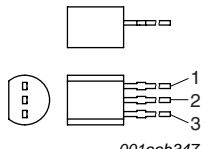
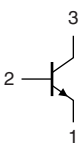
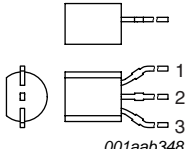
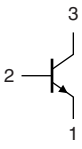
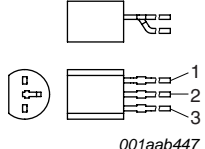
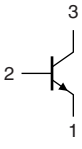
Table 2. Quick reference data

| Symbol    | Parameter                     | Conditions  | Min            | Typ | Max | Unit |
|-----------|-------------------------------|---|----------------|-----|-----|------|
| $V_{CEO}$ | collector-emitter voltage     | open base;<br>$I_C = 10 \text{ mA}$               | -              | -   | 45  | V    |
| $I_C$     | collector current (DC)        |   | -              | -   | 500 | mA   |
| $I_{CM}$  | peak collector current        |   | -              | -   | 1   | A    |
| $h_{FE}$  | DC current gain               | $I_C = 100 \text{ mA};$<br>$V_{CE} = 1 \text{ V}$ | <sup>[1]</sup> | -   | -   | -    |
|           | BC817; BC817W; BC337          |   |                | 100 | -   | 600  |
|           | BC817-16; BC817-16W; BC337-16 |   |                | 100 | -   | 250  |
|           | BC817-25; BC817-25W; BC337-25 |   |                | 160 | -   | 400  |
|           | BC817-40; BC817-40W; BC337-40 |   |                | 250 | -   | 600  |

[1] Pulse test:  $t_p \leq 300 \mu\text{s}$ ;  $\delta \leq 0.02$ .

## 2. Pinning information

**Table 3. Pinning**

| Pin                  | Description | Simplified outline  | Symbol  |
|----------------------|-------------|---|---|
| <b>SOT23</b>         |             |   |   |
| 1                    | base        |    | <br>sym021   |
| 2                    | emitter     |   |   |
| 3                    | collector   |   |   |
| <b>SOT323</b>        |             |   |   |
| 1                    | base        |    | <br>sym021   |
| 2                    | emitter     |   |   |
| 3                    | collector   |   |   |
| <b>SOT54</b>         |             |   |   |
| 1                    | emitter     |  | <br>sym026 |
| 2                    | base        |   |   |
| 3                    | collector   |   |   |
| <b>SOT54A</b>        |             |   |   |
| 1                    | emitter     |  | <br>sym026 |
| 2                    | base        |   |   |
| 3                    | collector   |   |   |
| <b>SOT54 variant</b> |             |   |   |
| 1                    | emitter     |  | <br>sym026 |
| 2                    | base        |   |   |
| 3                    | collector   |   |   |

### 3. Ordering information

**Table 4. Ordering information**

| Type number <sup>[1]</sup> | Package |   | Version |
|----------------------------|---------|---|---------|
|                            | Name    | Description   |         |
| BC817                      | -       | plastic surface mounted package; 3 leads                    | SOT23   |
| BC817W                     | SC-70   | plastic surface mounted package; 3 leads                    | SOT323  |
| BC337 <sup>[2]</sup>       | SC-43A  | plastic single-ended leaded (through hole) package; 3 leads | SOT54   |

[1] Valid for all available selection groups.

[2] Also available in SOT54A and SOT54 variant packages (see [Section 2](#) and [Section 9](#)).

### 4. Marking

**Table 5. Marking codes**

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| BC817       | 6D*                         |
| BC817-16    | 6A*                         |
| BC817-25    | 6B*                         |
| BC817-40    | 6C*                         |
| BC817W      | 6D*                         |
| BC817-16W   | 6A*                         |
| BC817-25W   | 6B*                         |
| BC817-40W   | 6C*                         |
| BC337       | C337                        |
| BC337-16    | C33716                      |
| BC337-25    | C33725                      |
| BC337-40    | C33740                      |

[1] \* = -: made in Hong Kong

\* = p: made in Hong Kong

\* = t: made in Malaysia

\* = W: made in China

## 5. Limiting values

**Table 6. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol    | Parameter                 | Conditions                               | Min      | Max  | Unit             |
|-----------|---------------------------|--|----------|------|------------------|
| $V_{CBO}$ | collector-base voltage    | open emitter                             | -        | 50   | V                |
| $V_{CEO}$ | collector-emitter voltage | open base;<br>$I_C = 10 \text{ mA}$      | -        | 45   | V                |
| $V_{EBO}$ | emitter-base voltage      | open collector                           | -        | 5    | V                |
| $I_C$     | collector current (DC)    |  | -        | 500  | mA               |
| $I_{CM}$  | peak collector current    |  | -        | 1    | A                |
| $I_{BM}$  | peak base current         |  | -        | 200  | mA               |
| $P_{tot}$ | total power dissipation   |  |          |      |                  |
|           | BC817                     | $T_{amb} \leq 25 \text{ }^\circ\text{C}$ | [1][2] - | 250  | mW               |
|           | BC817W                    | $T_{amb} \leq 25 \text{ }^\circ\text{C}$ | [1][2] - | 200  | mW               |
|           | BC337                     | $T_{amb} \leq 25 \text{ }^\circ\text{C}$ | [1][2] - | 625  | mW               |
| $T_{stg}$ | storage temperature       |  | -65      | +150 | $^\circ\text{C}$ |
| $T_j$     | junction temperature      |  | -        | 150  | $^\circ\text{C}$ |
| $T_{amb}$ | ambient temperature       |  | -65      | +150 | $^\circ\text{C}$ |

[1] Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

[2] Valid for all available selection groups.

## 6. Thermal characteristics

**Table 7. Thermal characteristics**

| Symbol        | Parameter                                   | Conditions                               | Min      | Typ | Max | Unit |
|---------------|---|--|----------|-----|-----|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient |  |          |     |     |      |
|               | BC817                                       | $T_{amb} \leq 25 \text{ }^\circ\text{C}$ | [1][2] - | -   | 500 | K/W  |
|               | BC817W                                      | $T_{amb} \leq 25 \text{ }^\circ\text{C}$ | [1][2] - | -   | 625 | K/W  |
|               | BC337                                       | $T_{amb} \leq 25 \text{ }^\circ\text{C}$ | [1][2] - | -   | 200 | K/W  |

[1] Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

[2] Valid for all available selection groups.

## 7. Characteristics

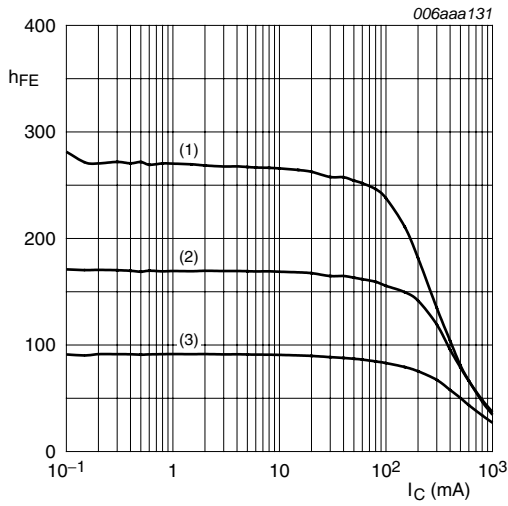
**Table 8. Characteristics**

$T_{amb} = 25\text{ °C}$  unless otherwise specified.

| Symbol      | Parameter                            | Conditions   | Min    | Typ | Max | Unit          |
|-------------|--------------------------------------|--|--------|-----|-----|---------------|
| $I_{CBO}$   | collector-base cut-off current       | $I_E = 0\text{ A}; V_{CB} = 20\text{ V}$                         | -      | -   | 100 | nA            |
|             |                                      | $I_E = 0\text{ A}; V_{CB} = 20\text{ V}; T_J = 150\text{ °C}$    | -      | -   | 5   | $\mu\text{A}$ |
| $I_{EBO}$   | emitter-base cut-off current         | $I_C = 0\text{ A}; V_{EB} = 5\text{ V}$                          | -      | -   | 100 | nA            |
| $h_{FE}$    | DC current gain                      | $I_C = 100\text{ mA}; V_{CE} = 1\text{ V}$                       | [1]    |     |     |               |
|             |                                      | BC817; BC817W; BC337   | 100    | -   | 600 |               |
|             |                                      | BC817-16; BC817-16W;<br>BC337-16                                 | 100    | -   | 250 |               |
|             |                                      | BC817-25; BC817-25W;<br>BC337-25                                 | 160    | -   | 400 |               |
|             |                                      | BC817-40; BC817-40W;<br>BC337-40                                 | 250    | -   | 600 |               |
| $h_{FE}$    | DC current gain                      | $I_C = 500\text{ mA}; V_{CE} = 1\text{ V}$                       | [1] 40 | -   | -   |               |
| $V_{CEsat}$ | collector-emitter saturation voltage | $I_C = 500\text{ mA}; I_B = 50\text{ mA}$                        | [1] -  | -   | 700 | mV            |
| $V_{BE}$    | base-emitter voltage                 | $I_C = 500\text{ mA}; V_{CE} = 1\text{ V}$                       | [2] -  | -   | 1.2 | V             |
| $C_c$       | collector capacitance                | $I_E = i_e = 0\text{ A}; V_{CB} = 10\text{ V}; f = 1\text{ MHz}$ | -      | 3   | -   | pF            |
| $f_T$       | transition frequency                 | $I_C = 10\text{ mA}; V_{CE} = 5\text{ V}; f = 100\text{ MHz}$    | 100    | -   | -   | MHz           |

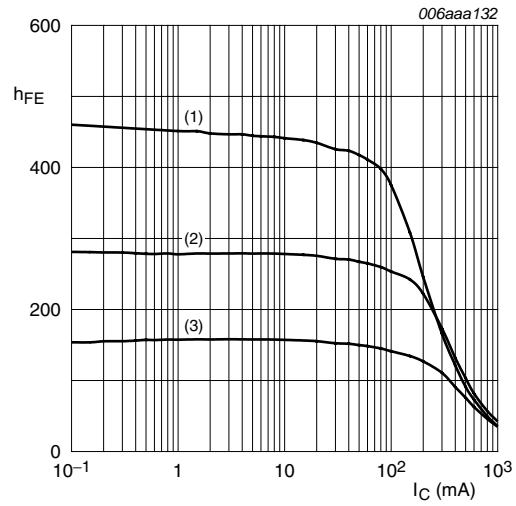
[1] Pulse test:  $t_p \leq 300\text{ }\mu\text{s}$ ;  $\delta \leq 0.02$ .

[2]  $V_{BE}$  decreases by approximately 2 mV/K with increasing temperature.



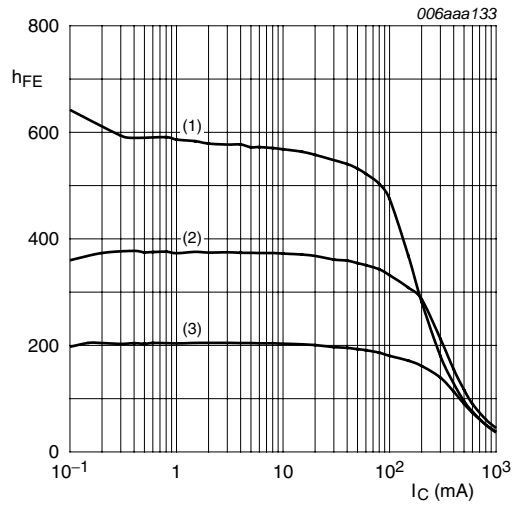
- $V_{CE} = 1\text{ V}$   
 (1)  $T_{amb} = 150\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -55\text{ °C}$

**Fig 1. Selection -16: DC current gain as a function of collector current; typical values**



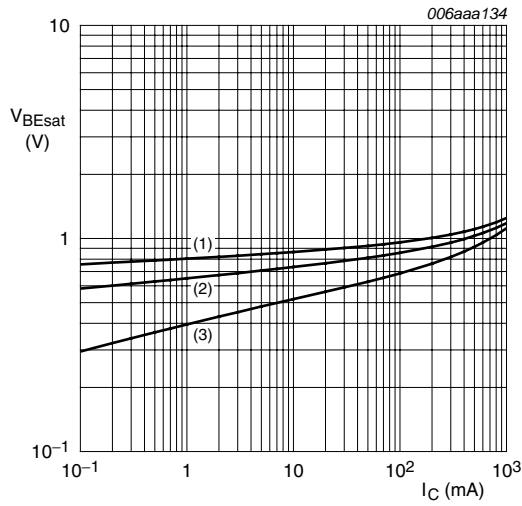
- $V_{CE} = 1\text{ V}$   
 (1)  $T_{amb} = 150\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -55\text{ °C}$

**Fig 2. Selection -25: DC current gain as a function of collector current; typical values**



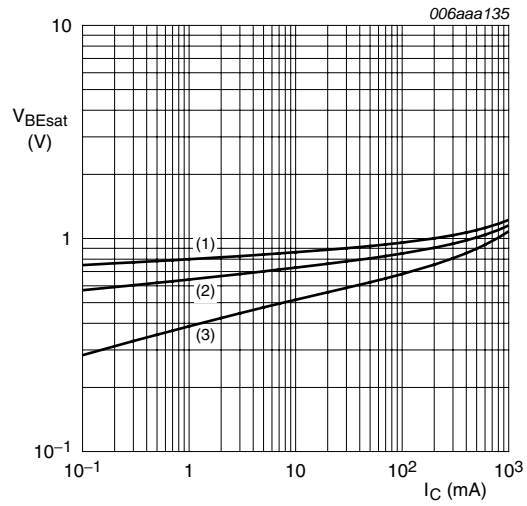
- $V_{CE} = 1\text{ V}$   
 (1)  $T_{amb} = 150\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -55\text{ °C}$

**Fig 3. Selection -40: DC current gain as a function of collector current; typical values**



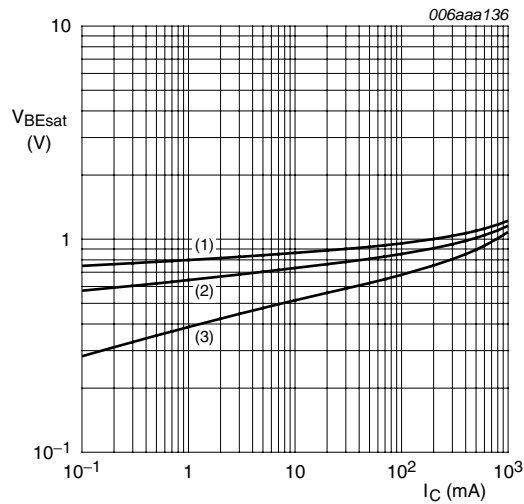
- $I_C/I_B = 10$
- (1)  $T_{amb} = -55\text{ °C}$
  - (2)  $T_{amb} = 25\text{ °C}$
  - (3)  $T_{amb} = 150\text{ °C}$

**Fig 4. Selection -16: Base-emitter saturation voltage as a function of collector current; typical values**



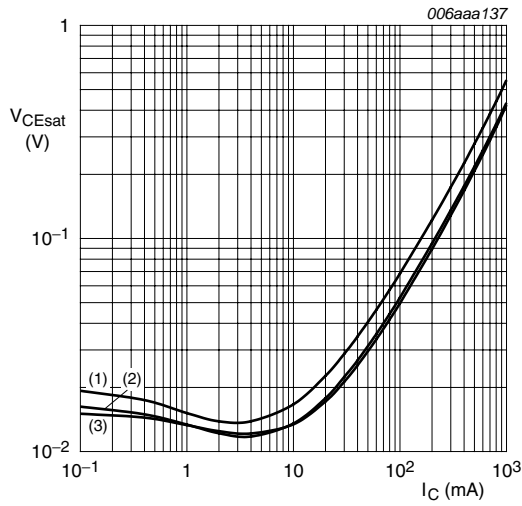
- $I_C/I_B = 10$
- (1)  $T_{amb} = -55\text{ °C}$
  - (2)  $T_{amb} = 25\text{ °C}$
  - (3)  $T_{amb} = 150\text{ °C}$

**Fig 5. Selection -25: Base-emitter saturation voltage as a function of collector current; typical values**



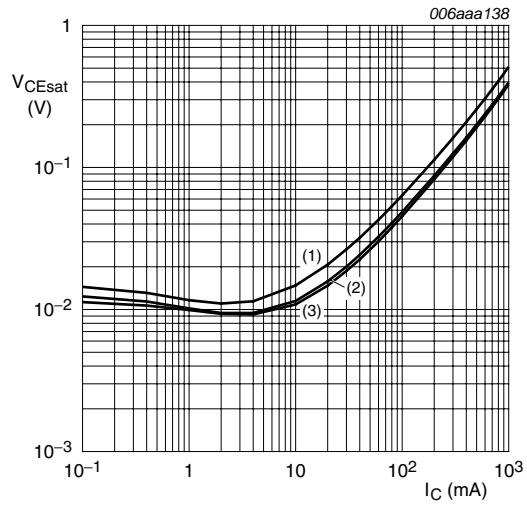
- $I_C/I_B = 10$
- (1)  $T_{amb} = -55\text{ °C}$
  - (2)  $T_{amb} = 25\text{ °C}$
  - (3)  $T_{amb} = 150\text{ °C}$

**Fig 6. Selection -40: Base-emitter saturation voltage as a function of collector current; typical values**



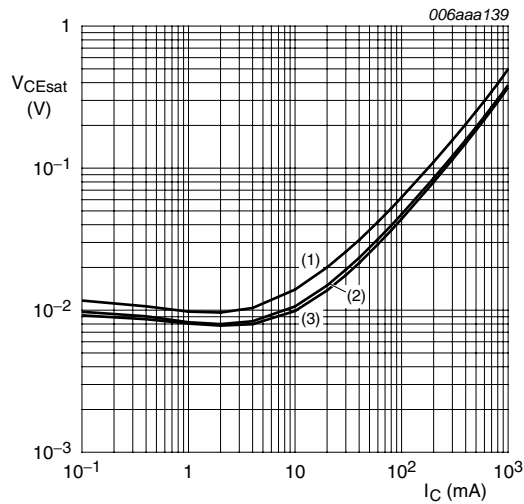
- $I_C/I_B = 10$
- (1)  $T_{amb} = 150\text{ °C}$
  - (2)  $T_{amb} = 25\text{ °C}$
  - (3)  $T_{amb} = -55\text{ °C}$

**Fig 7. Selection -16: Collector-emitter saturation voltage as a function of collector current; typical values**



- $I_C/I_B = 10$
- (1)  $T_{amb} = 150\text{ °C}$
  - (2)  $T_{amb} = 25\text{ °C}$
  - (3)  $T_{amb} = -55\text{ °C}$

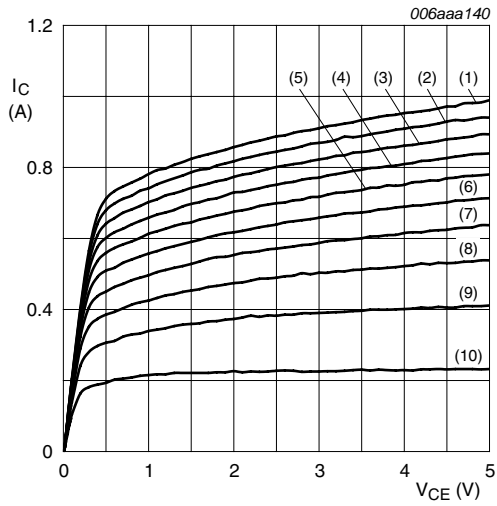
**Fig 8. Selection -25: Collector-emitter saturation voltage as a function of collector current; typical values**



- $I_C/I_B = 10$
- (1)  $T_{amb} = 150\text{ °C}$
  - (2)  $T_{amb} = 25\text{ °C}$
  - (3)  $T_{amb} = -55\text{ °C}$

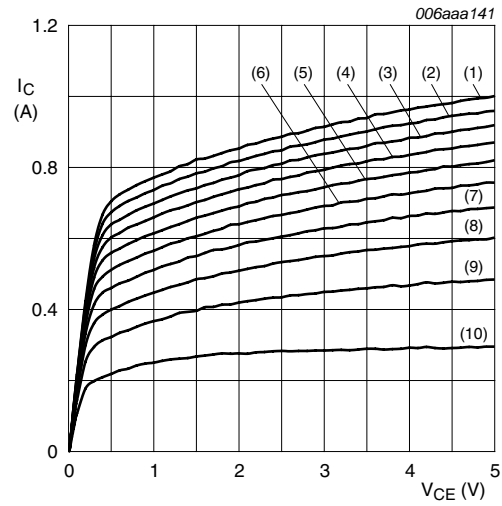
**Fig 9. Selection -40: Collector-emitter saturation voltage as a function of collector current; typical values**





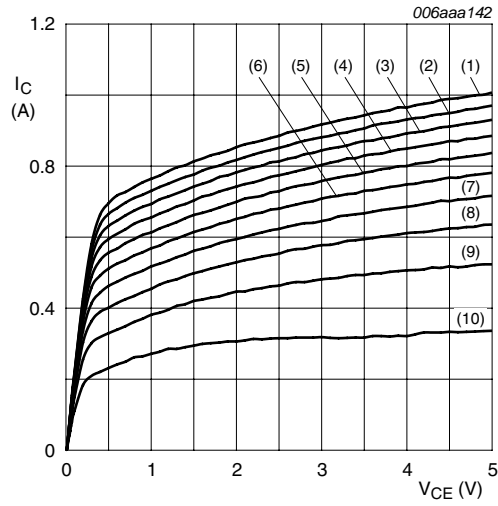
- $T_{amb} = 25\text{ }^\circ\text{C}$
- (1)  $I_B = 16.0\text{ mA}$
  - (2)  $I_B = 14.4\text{ mA}$
  - (3)  $I_B = 12.8\text{ mA}$
  - (4)  $I_B = 11.2\text{ mA}$
  - (5)  $I_B = 9.6\text{ mA}$
  - (6)  $I_B = 8.0\text{ mA}$
  - (7)  $I_B = 6.4\text{ mA}$
  - (8)  $I_B = 4.8\text{ mA}$
  - (9)  $I_B = 3.2\text{ mA}$
  - (10)  $I_B = 1.6\text{ mA}$

**Fig 10. Selection -16: Collector current as a function of collector-emitter voltage; typical values**



- $T_{amb} = 25\text{ }^\circ\text{C}$
- (1)  $I_B = 13.0\text{ mA}$
  - (2)  $I_B = 11.7\text{ mA}$
  - (3)  $I_B = 10.4\text{ mA}$
  - (4)  $I_B = 9.1\text{ mA}$
  - (5)  $I_B = 7.8\text{ mA}$
  - (6)  $I_B = 6.5\text{ mA}$
  - (7)  $I_B = 5.2\text{ mA}$
  - (8)  $I_B = 3.9\text{ mA}$
  - (9)  $I_B = 2.6\text{ mA}$
  - (10)  $I_B = 1.3\text{ mA}$

**Fig 11. Selection -25: Collector current as a function of collector-emitter voltage; typical values**



- $T_{amb} = 25\text{ }^{\circ}\text{C}$
- (1)  $I_B = 12.0\text{ mA}$
  - (2)  $I_B = 10.8\text{ mA}$
  - (3)  $I_B = 9.6\text{ mA}$
  - (4)  $I_B = 8.4\text{ mA}$
  - (5)  $I_B = 7.2\text{ mA}$
  - (6)  $I_B = 6.0\text{ mA}$
  - (7)  $I_B = 4.8\text{ mA}$
  - (8)  $I_B = 3.6\text{ mA}$
  - (9)  $I_B = 2.4\text{ mA}$
  - (10)  $I_B = 1.2\text{ mA}$

Fig 12. Selection -40: Collector current as a function of collector-emitter voltage; typical values

8. Package outline

Plastic surface-mounted package; 3 leads

SOT23

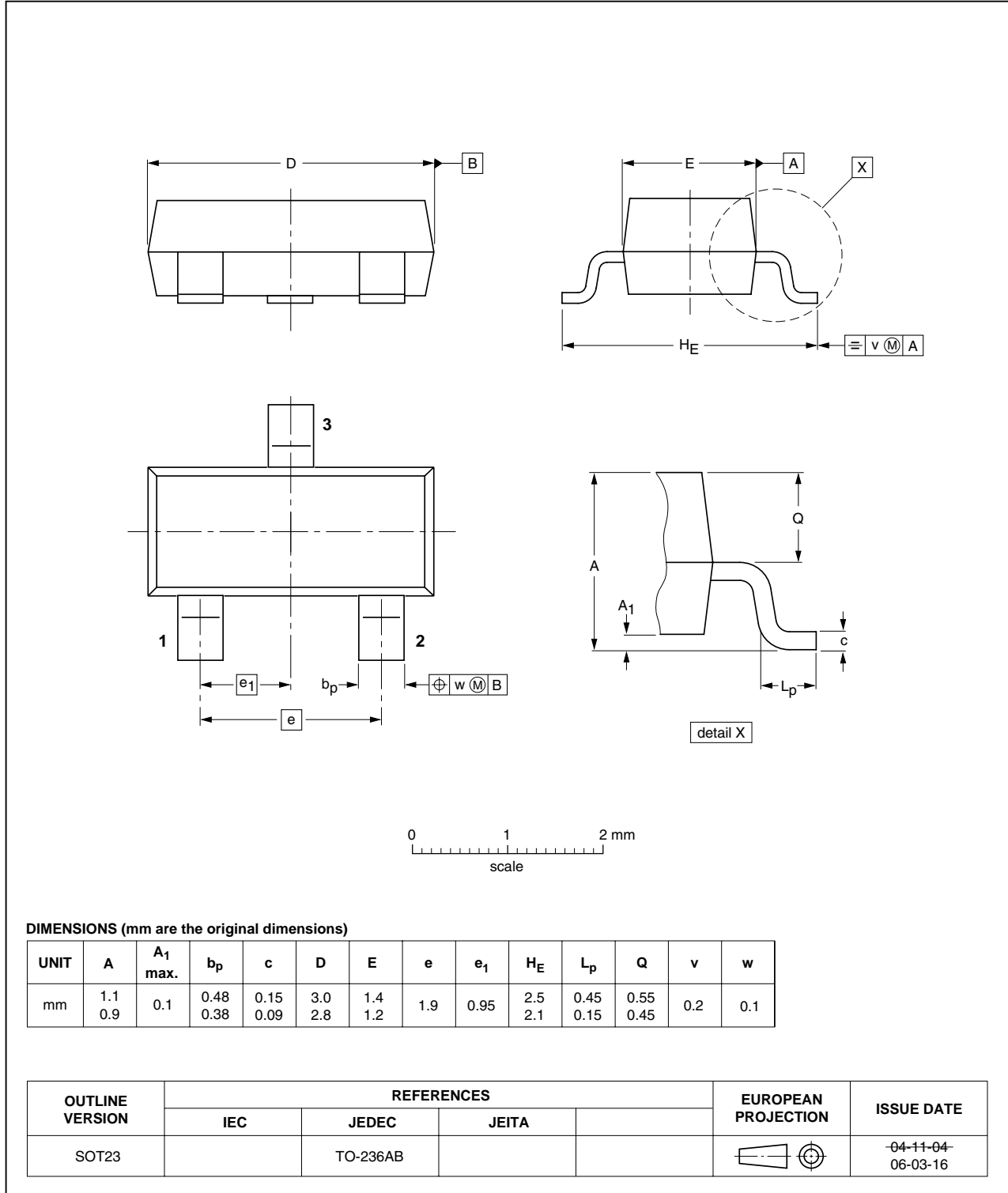


Fig 13. Package outline SOT23 (TO-236AB)

Plastic surface-mounted package; 3 leads

SOT323

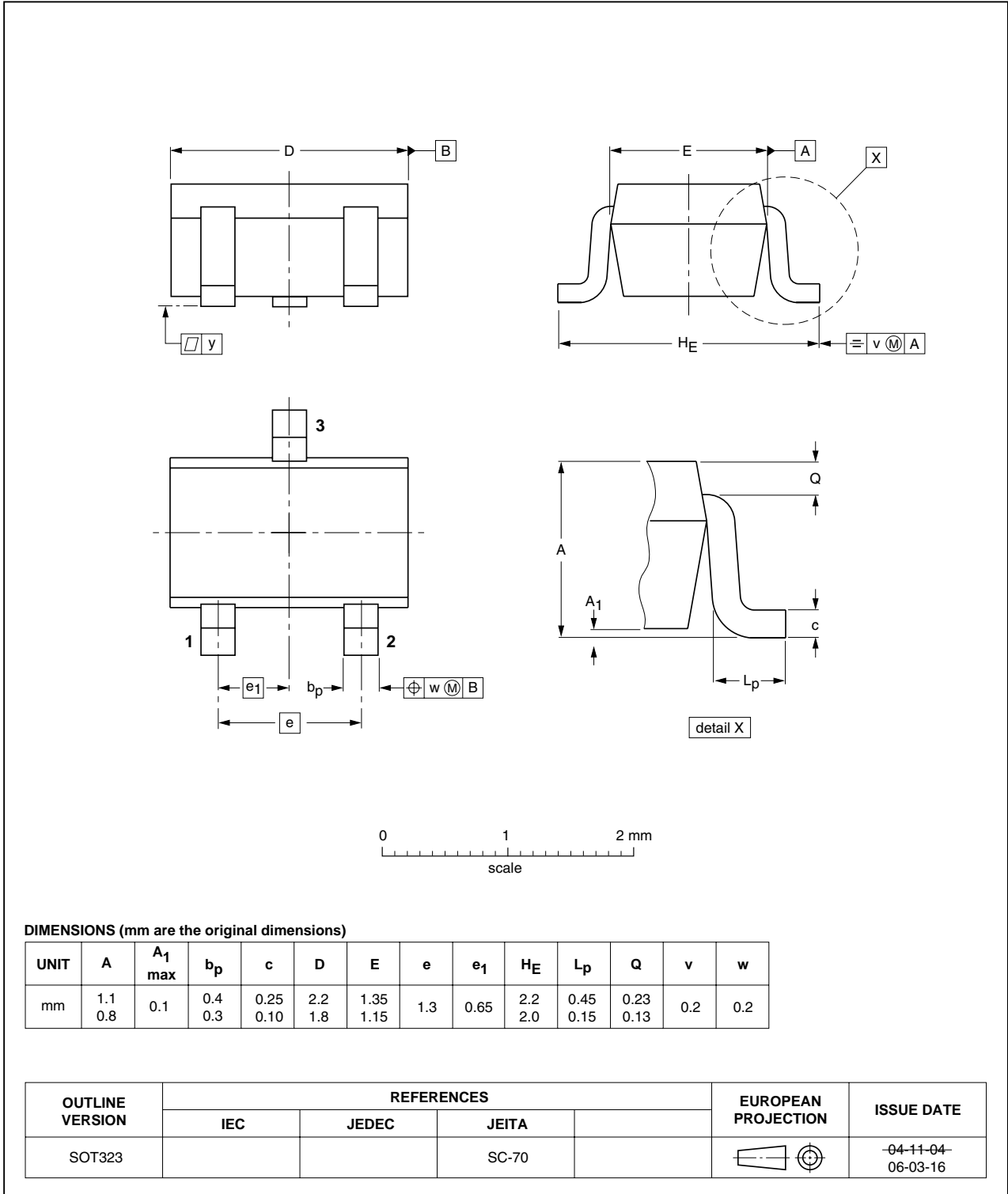


Fig 14. Package outline SOT323 (SC-70)

Plastic single-ended leaded (through hole) package; 3 leads

SOT54

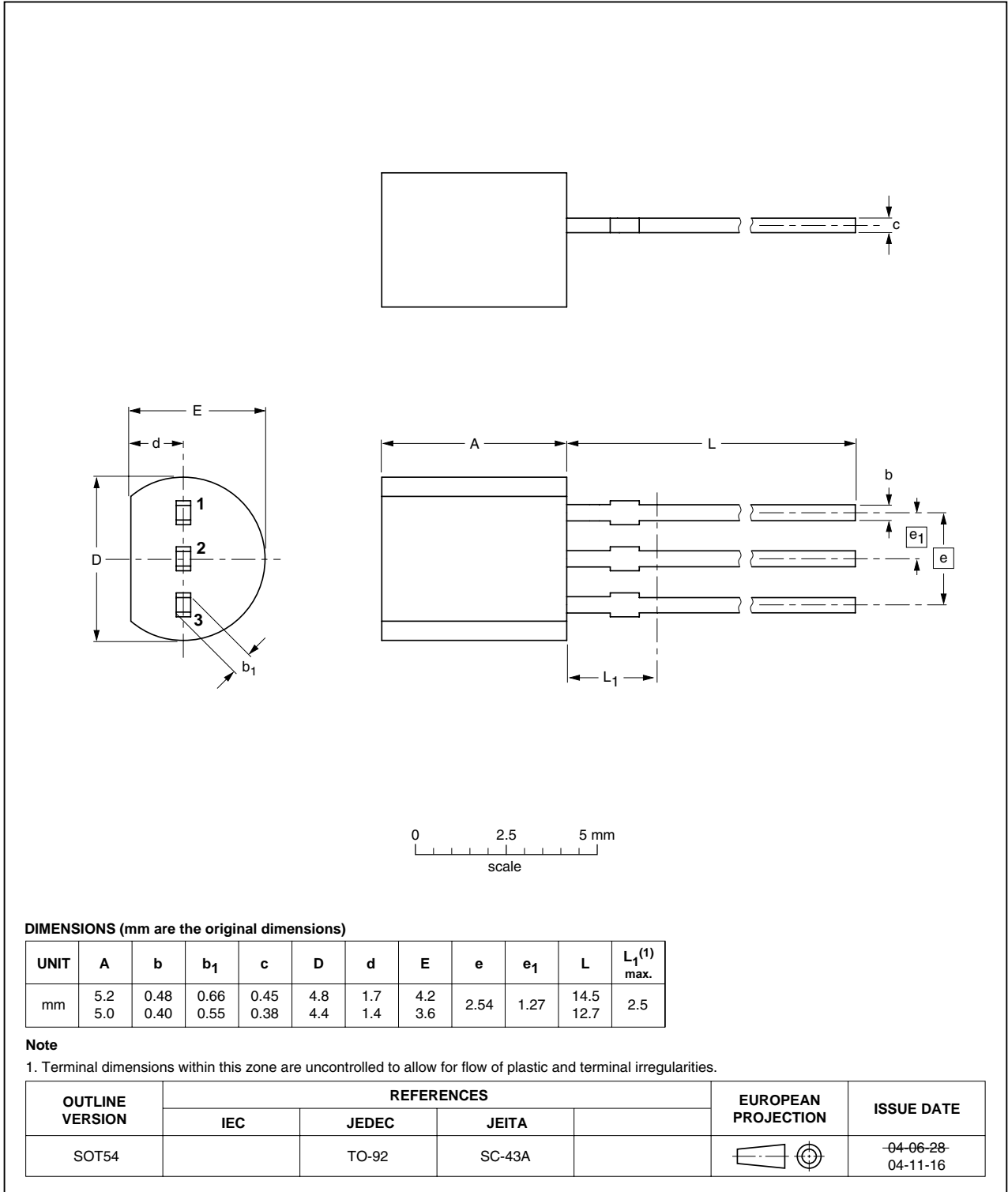


Fig 15. Package outline SOT54 (SC-43A/TO-92)

Plastic single-ended leaded (through hole) package; 3 leads (wide pitch)

SOT54A

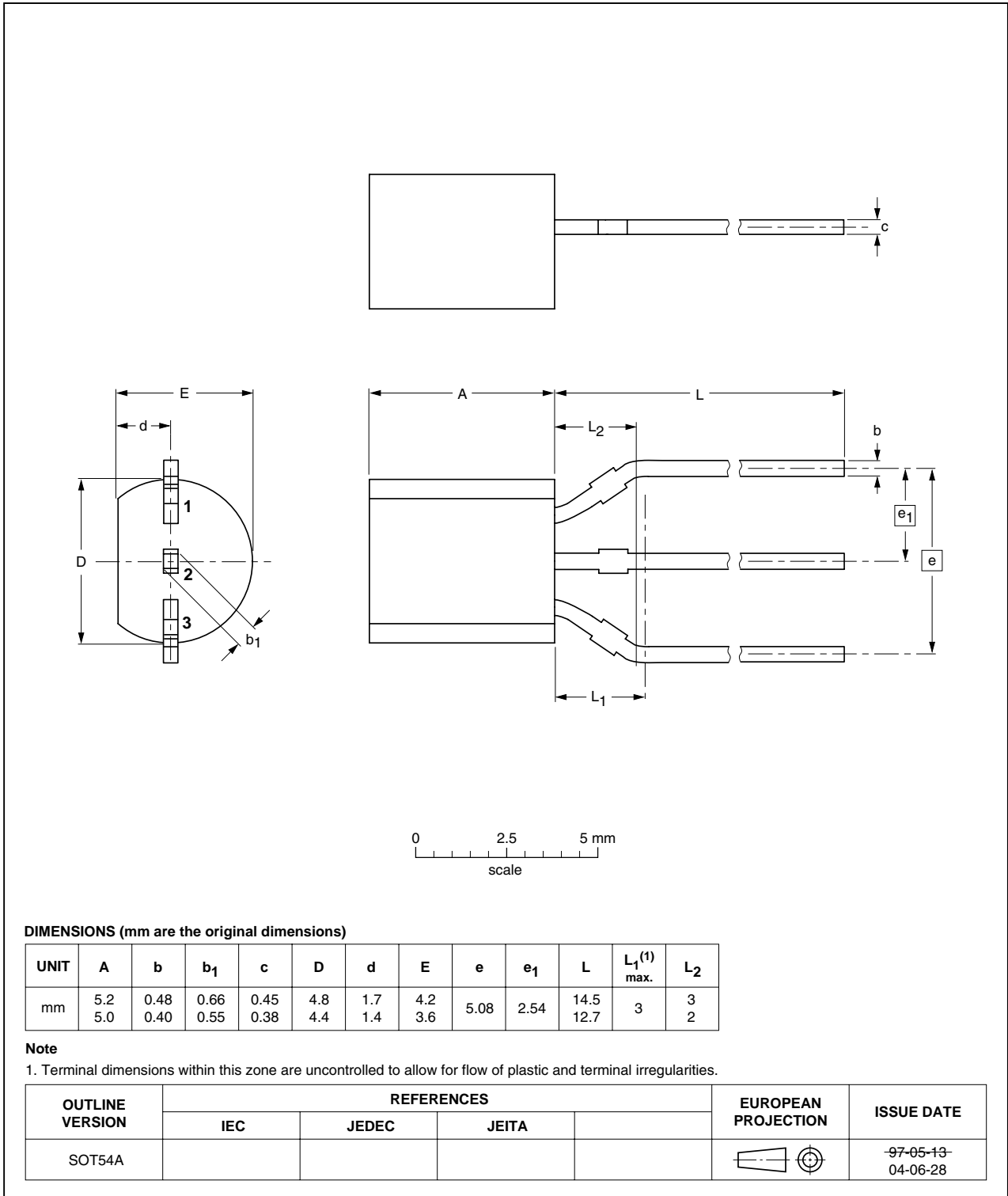


Fig 16. Package outline SOT54A

Plastic single-ended leaded (through hole) package; 3 leads (on-circle)

SOT54 variant

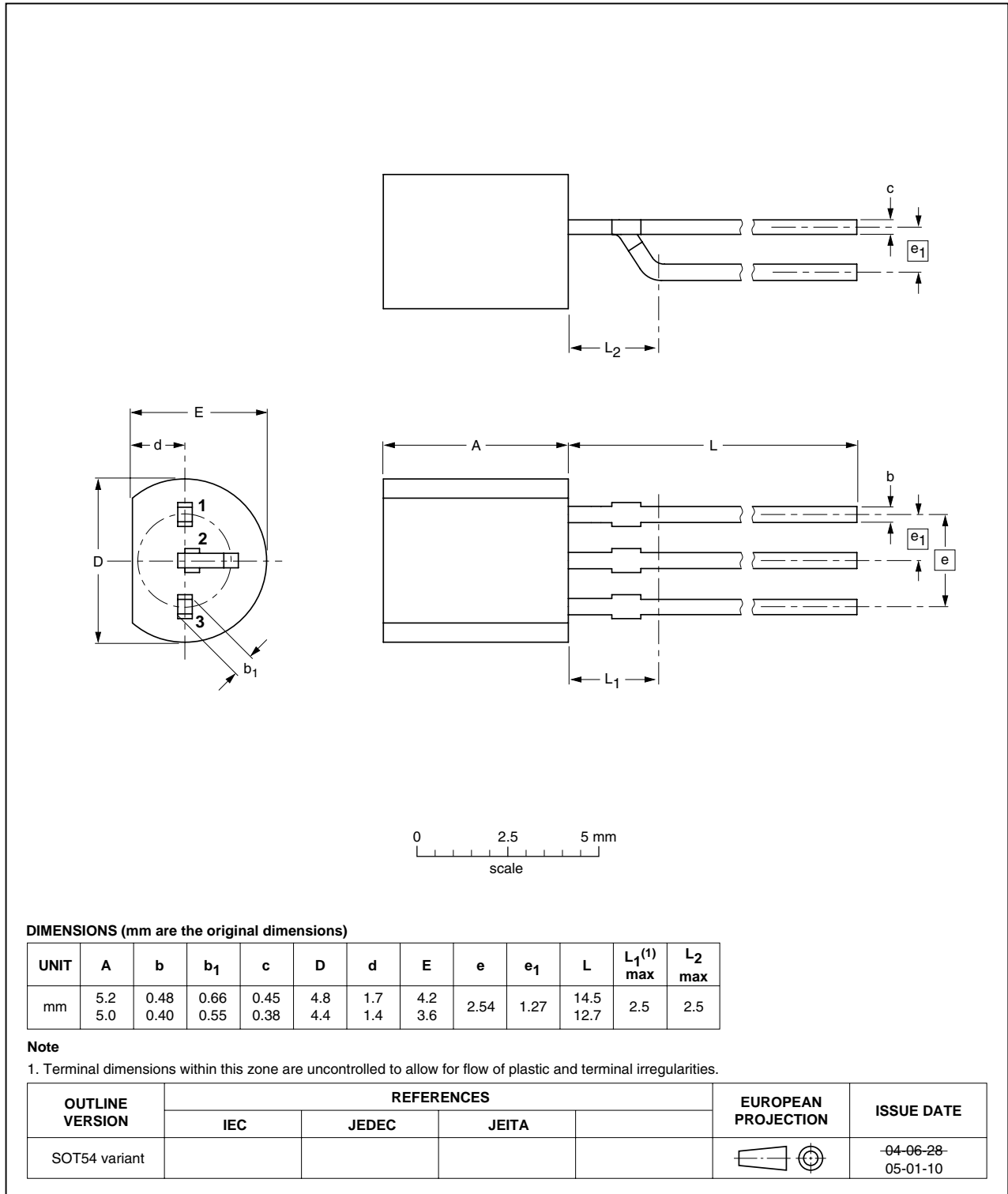


Fig 17. Package outline SOT54 variant

## 9. Packing information

**Table 9. Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

| Type number | Package        | Description                     | Packing quantity |      |       |
|-------------|----------------|---------------------------------|------------------|------|-------|
|             |                |                                 | 3000             | 5000 | 10000 |
| BC817       | SOT23          | 4 mm pitch, 8 mm tape and reel  | -215             | -    | -235  |
| BC817W      | SOT323         | 4 mm pitch, 8 mm tape and reel  | -115             | -    | -135  |
| BC337       | SOT54          | bulk, straight leads            | -                | -412 | -     |
| BC337       | SOT54A         | tape and reel, wide pitch       | -                | -    | -116  |
| BC337       | SOT54A         | tape ammpack, wide pitch        | -                | -    | -126  |
| BC337       | SOT 54 variant | bulk, delta pinning (on-circle) | -                | -112 | -     |

[1] For further information and the availability of packing methods, see [Section 12](#).



## 10. Revision history

**Table 10. Revision history**

| Document ID              | Release date | Data sheet status   | Change notice   | Supersedes                           |
|--------------------------|--------------|---|-----------------|--------------------------------------|
| BC817_BC817W_<br>BC337_6 | 20091117     | Product data sheet  | -               | BC817_BC817W_<br>BC337_5             |
| Modifications:           |              | <ul style="list-style-type: none"> <li>• This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content.</li> <li>• <a href="#">Table 3 "Pinning"</a>: updated</li> <li>• <a href="#">Figure 13 "Package outline SOT23 (TO-236AB)"</a>: updated</li> <li>• <a href="#">Figure 14 "Package outline SOT323 (SC-70)"</a>: updated</li> </ul> |                 |                                      |
| BC817_BC817W_<br>BC337_5 | 20050121     | Product data sheet  | CPCN200302007F1 | BC817_4;<br>BC817W_SER_4;<br>BC337_3 |
| BC817_4                  | 20040105     | Product specification   | -               | BC817_3                              |
| BC817W_SER_4             | 20040225     | Product specification   | -               | BC817W_SER_3                         |
| BC337_3                  | 19990415     | Product specification   | -               | BC337_338_CNV_2                      |

## 11. Legal information

### 11.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

### 11.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

**Short data sheet** — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

### 11.3 Disclaimers

**General** — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

**Right to make changes** — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use** — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental

damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

**Limiting values** — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

**Terms and conditions of sale** — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nxp.com/profile/terms>, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

### 11.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## 12. Contact information

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

**13. Contents**

**1 Product profile . . . . . 1**

1.1 General description . . . . . 1

1.2 Features . . . . . 1

1.3 Applications . . . . . 1

1.4 Quick reference data . . . . . 1

**2 Pinning information . . . . . 2**

**3 Ordering information . . . . . 3**

**4 Marking . . . . . 3**

**5 Limiting values . . . . . 4**

**6 Thermal characteristics . . . . . 4**

**7 Characteristics . . . . . 5**

**8 Package outline . . . . . 11**

**9 Packing information . . . . . 16**

**10 Revision history . . . . . 17**

**11 Legal information . . . . . 18**

11.1 Data sheet status . . . . . 18

11.2 Definitions . . . . . 18

11.3 Disclaimers . . . . . 18

11.4 Trademarks . . . . . 18

**12 Contact information . . . . . 18**

**13 Contents . . . . . 19**



Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2009. **All rights reserved.**

For more information, please visit: <http://www.nxp.com>  
 For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

Date of release: 17 November 2009

Document identifier: BC817\_BC817W\_BC337\_6